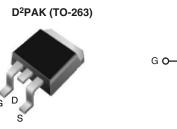


Vishay Siliconix

Power MOSFET

| PRODUCT SUMMARY | | | | | | |
|----------------------------|----------------|------|--|--|--|--|
| V _{DS} (V) | 200 | | | | | |
| R _{DS(on)} (Ω) | $V_{GS} = 5 V$ | 0.40 | | | | |
| Q _g (Max.) (nC) | 40 | | | | | |
| Q _{gs} (nC) | 5.5 | | | | | |
| Q _{gd} (nC) | 24 | | | | | |
| Configuration | Single | | | | | |



S N-Channel MOSFET

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Surface Mount
- Available in Tape and Reel
- Dynamic dV/dt Rating
- Repetitive Avalanche Rated
- Logic-Level Gate Drive •
- R_{DS(on)} Specified at V_{GS} = 4 V and 5 V
 150 °C Operating Temperature
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

Third generation Power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The D²PAK (TO-263) is a surface mount power package capable of accommodating die size up to HEX-4. It provides the highest power capability and the lowest possible on-resistance in any existing surface mount package. The D²PAK (TO-263) is suitable for high current applications because of its low internal connection resistance and can dissipate up to 2.0 W in a typical surface mount application.

| ORDERING INFORMATION | | | | | | |
|---------------------------------|-----------------------------|------------------------------|-----------------------------|--|--|--|
| Package | D ² PAK (TO-263) | D ² PAK (TO-263) | D ² PAK (TO-263) | | | |
| Lead (Pb)-free and Halogen-free | SiHL630S-GE3 | SiHL630STRR-GE3 ^a | SiHL630STRL-GE3ª | | | |
| Load (Pb) free | IRL630SPbF | IRL630STRRPbF ^a | IRL630STRLPbF ^a | | | |
| Lead (Pb)-free | SiHL630S-E3 | SiHL630STR-E3 ^a | SiHL630STL-E3ª | | | |

Note

a. See device orientation.

| ABSOLUTE MAXIMUM RATINGS (T _C | = 25 °C, unl | ess otherwis | se noted) | | |
|----------------------------------------------------|-----------------------------------|---------------------------------------------------|------------------|------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT | | |
| Drain-Source Voltage | V _{DS} | 200 | V | | |
| Gate-Source Voltage | V _{GS} | ± 10 | v | | |
| Continuous Drain Current | Ver at 5 V | T _C = 25 °C | ID | 9.0 | |
| Continuous Drain Current | V _{GS} at 5 V | T _C = 25 °C T _C = 100 °C | | 5.7 | A |
| Pulsed Drain Current ^a | | | I _{DM} | 36 | |
| Linear Derating Factor | | | | 0.59 | W/°C |
| Linear Derating Factor (PCB Mount) ^e | | | 0.025 | VV/C | |
| Single Pulse Avalanche Energy ^b | | E _{AS} | 250 | mJ | |
| Avalanche Current ^a | | | I _{AR} | 9.0 | A |
| Repetiitive Avalanche Energy ^a | | | E _{AR} | 7.4 | mJ |
| Maximum Power Dissipation | 25 °C | Р | 74 | w | |
| Maximum Power Dissipation (PCB Mount) ^e | P _D | 3.1 | vv | | |
| Peak Diode Recovery dV/dtc | | dV/dt | 5.0 | V/ns | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to + 150 | - °C | | |
| Soldering Recommendations (Peak Temperature) | 10 s | - | 300 ^d | | |

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).

b. V_{DD} = 25V, starting T_J = 25 °C, L = 4.6 mH, R_g = 25 Ω , I_{AS} = 9.0 A (see fig. 12).

c. $I_{SD} \le 9.0$ A, dI/dt ≤ 120 A/µs, $V_{DD} \le V_{DS}$, $T_{J} \le 150$ °C.

d. 1.6 mm from case.

e. When mounted on 1" square PCB (FR-4 or G-10 material).

* Pb containing terminations are not RoHS compliant, exemptions may apply

Document Number: 90390 S11-1044-Rev. C, 30-May-11 www.vishay.com



COMPLIANT

HALOGEN FREE

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| THERMAL RESISTANCE RATINGS | | | | | | | |
|---------------------------------------------------------|-------------------|------|------|------|--|--|--|
| PARAMETER | SYMBOL | TYP. | MAX. | UNIT | | | |
| Maximum Junction-to-Ambient | R _{thJA} | - | 62 | | | | |
| Maximum Junction-to-Ambient (PCB Mount) ^a | R _{thJA} | - | 40 | °C/W | | | |
| Maximum Junction-to-Case (Drain) | R _{thJC} | - | 1.7 | | | | |

Note

a. When mounted on 1" square PCB (FR-4 or G-10 material).

| PARAMETER | SYMBOL TEST CONDITIONS | | | MIN. | TYP. | MAX. | UNIT |
|-------------------------------------------|-----------------------------------------------------------------------------------|---------------------------------------------------------------------------------|------------------------------------------------------------------------------------|------|-------|------|------|
| Static | | | | | • | • | |
| Drain-Source Breakdown Voltage | V _{DS} | V _{GS} | = 0, I _D = 250 μA | 200 | - | - | V |
| V _{DS} Temperature Coefficient | $\Delta V_{DS}/T_J$ | Reference | Reference to 25 °C, $I_D = 1 \text{ mA}$ | | | - | V/°C |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | 1.0 | - | 2.0 | V | |
| Gate-Source Leakage | I _{GSS} | | - | - | ± 100 | nA | |
| Zana Oata Maltana Dusia Orimont | | $V_{DS} = 200 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | - | - | 25 | |
| zero Gate voltage Drain Current | Cate Voltage Drain Current I_{DSS} $V_{DS} = 160 V, V_{GS} = 0 V, T_J = 125 °C$ | | ∕, V _{GS} = 0 V, T _J = 125 °C | - | - | 250 | μA |
| Drain-Source On-State Resistance | D | $V_{GS} = 5.0 V$ | I _D = 5.4 A ^b | - | - | 0.40 | Q |
| Drain-Source On-State Resistance | R _{DS(on)} | $V_{GS} = 4.0 V$ | $I_D = 4.5 \text{ A}^{b}$ | - | - | 0.50 | 52 |
| Forward Transconductance | g fs | V _{DS} = | = 50 V, I _D = 5.4 A ^b | 4.8 | - | - | S |
| Dynamic | | · | | | | | |
| Input Capacitance | C _{iss} | | $V_{GS} = 0 V$, | - | 1100 | - | |
| Output Capacitance | C _{oss} | | $V_{DS} = 25 V,$ | - | 220 | - | pF |
| Reverse Transfer Capacitance | C _{rss} | f = 1. | .0 MHz, see fig. 5 | - | 70 | - | 1 |
| Total Gate Charge | Qg | | | - | - | 40 | nC |
| Gate-Source Charge | Q _{gs} | V _{GS} = 10 V | I _D = 9.0 A, V _{DS} = 160 V, see fig. 6 and 13 ^b | - | - | 5.5 | |
| Gate-Drain Charge | Q _{gd} | 1 | | - | - | 24 | |
| Turn-On Delay Time | t _{d(on)} | | | - | 8.0 | - | - ns |
| Rise Time | t _r | V _{DD} = | 100 V, I _D = 9.0 A, | - | 57 | - | |
| Turn-Off Delay Time | t _{d(off)} | $R_g = 6.0 \Omega$, | $R_D = 11 \Omega$, see fig. 10^{b} | - | 38 | - | |
| Fall Time | t _f | | | - | 33 | - | |
| Internal Drain Inductance | L _D | Between lead 6 mm (0.25") 1 | , | - | 4.5 | - | |
| Internal Source Inductance | L _S | package and die contact | package and center of | | | - | - nH |
| Drain-Source Body Diode Characteristic | s | | | | | | |
| Continuous Source-Drain Diode Current | I _S | MOSFET sym showing the | | - | - | 9.0 | A |
| Pulsed Diode Forward Current ^a | I _{SM} | integral revers p - n junction | | - | - | 36 | |
| Body Diode Voltage | V_{SD} | T _J = 25 °C | $I_{\rm S} = 9.0 \text{ A}, V_{\rm GS} = 0 \text{ V}^{\rm b}$ | - | - | 2.0 | V |
| Body Diode Reverse Recovery Time | t _{rr} | T 05 00 1 | = 9.0 A, dl/dt = 100 A/µs ^b | - | 230 | 350 | ns |
| Body Diode Reverse Recovery Charge | Q _{rr} | $I_{\rm J} = 25 {}^{\circ}{\rm C}, I_{\rm F}$ | - | 1.7 | 2.6 | μC | |
| Forward Turn-On Time | t _{on} | Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D) | | | | | |

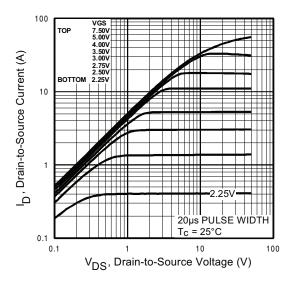
Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11). b. Pulse width \leq 300 µs; duty cycle \leq 2 %.

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Fig. 1 - Typical Output Characteristics, T_C = 25 °C

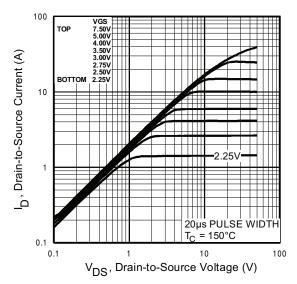
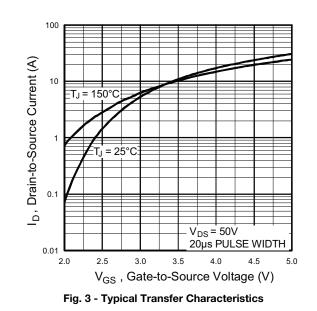


Fig. 2 - Typical Output Characteristics, T_C = 150 °C



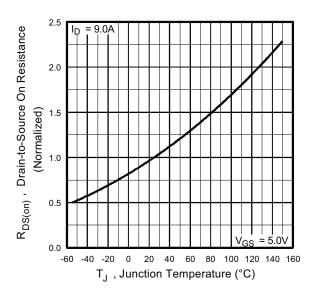


Fig. 4 - Normalized On-Resistance vs. Temperature

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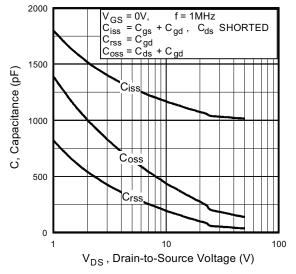


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

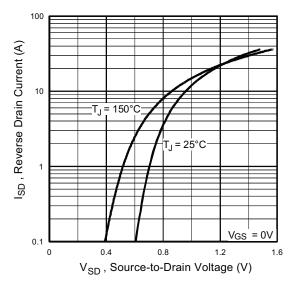


Fig. 7 - Typical Source-Drain Diode Forward Voltage

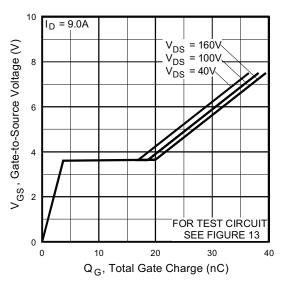


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

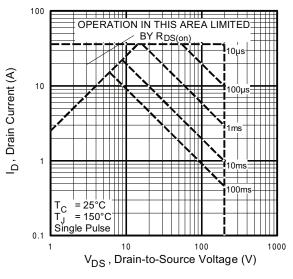


Fig. 8 - Maximum Safe Operating Area

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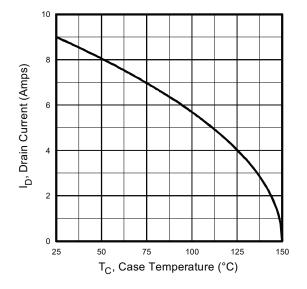


Fig. 9 - Maximum Drain Current vs. Case Temperature

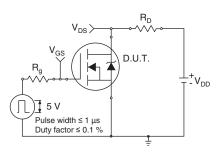


Fig. 10a - Switching Time Test Circuit

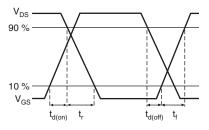


Fig. 10b - Switching Time Waveforms

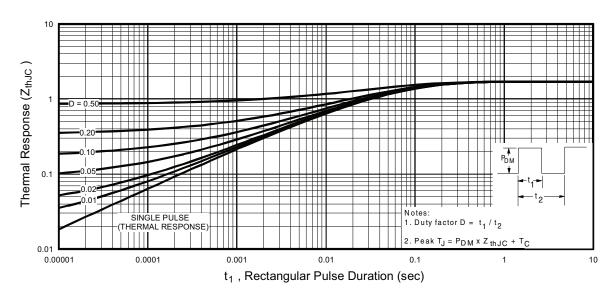


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

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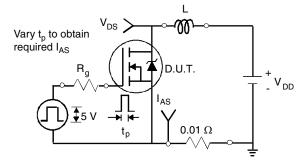


Fig. 12a - Unclamped Inductive Test Circuit

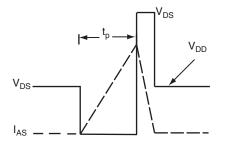


Fig. 12b - Unclamped Inductive Waveforms

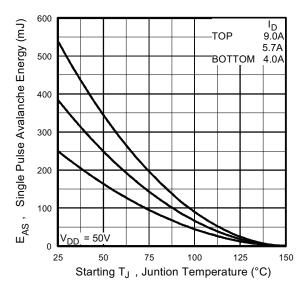
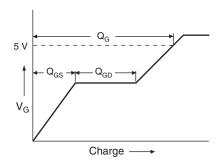


Fig. 12c - Maximum Avalanche Energy vs. Drain Current





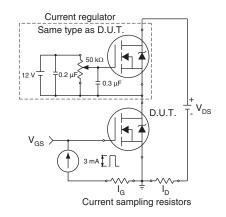
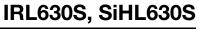


Fig. 13b - Gate Charge Test Circuit

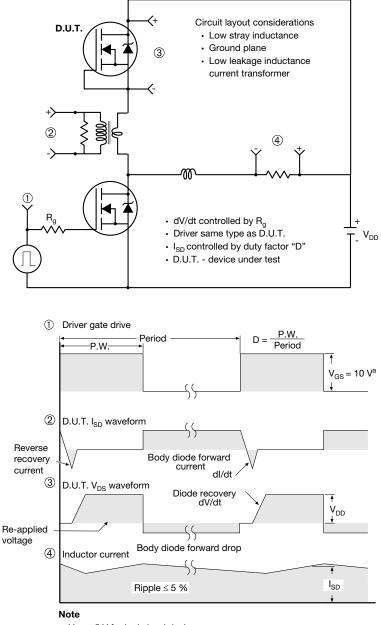
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Peak Diode Recovery dV/dt Test Circuit



a. $V_{GS} = 5 V$ for logic level devices

Fig. 14 - For N-Channel

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H

A1

B

Gauge plane

L3

Detail "A" Rotated 90° CW scale 8:1

0° to 8° **Vishay Siliconix**

Seating plane

TO-263AB (HIGH VOLTAGE)

/3 ⁄4 A

н

∕₅∖

Detail A

(Datum A)

D

 $\underline{4}$ 11

| | 2 | - | Y 2 x b2 2 x b ⊕ 0.010 @ A(| ■ ating 5 b1, b b1, b b1, b c) c) c) c) c) c) c) c) c) c) | $\begin{array}{c} c_{1} \\ c_{1} \\ c_{2} \\ c_{3} \\ c_{4} \\ c_{5} \\ c_{5} \\ c_{7} \\$ | a - 1 | | Ū. | 1 <u>4</u> | |
|--------------------------------|----------------------------------------------|----------------------------------------------|----------------------------------------------------|-----------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|-----------------------------------------|-------------------------------------------|--------------------------------------------|------------------------------------------------|
| | MILLIN | IETERS | INCHES | | | | MILLIMETERS | | INCHES | |
| DIM. | MIN. | MAX. | MIN. | MAX. | | DIM. | MIN. | MAX. | MIN. | MAX. |
| А | 4.06 | 4.83 | 0.160 | 0.190 | | D1 | 6.86 | - | 0.270 | - |
| | | | | 0.010 | | - | | 10.07 | 0.000 | 0.420 |
| A1 | 0.00 | 0.25 | 0.000 | 0.010 | | E | 9.65 | 10.67 | 0.380 | 0.120 |
| A1 b | 0.00 0.51 | 0.25 0.99 | 0.000 | 0.010 | | E1 | 9.65 6.22 | - 10.67 | 0.380 | - |
| | | | | | | | 6.22 | - 10.67 - BSC | 0.245 | - BSC |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | E1 | 6.22 | - | 0.245 | - |
| b b1 | 0.51 0.51 | 0.99 0.89 | 0.020 0.020 | 0.039 0.035 | | E1 e | 6.22 2.54 | - BSC | 0.245 | -) BSC |
| b b1 b2 | 0.51 0.51 1.14 | 0.99 0.89 1.78 | 0.020 0.020 0.045 | 0.039 0.035 0.070 | | E1 e H | 6.22 2.54 14.61 | - BSC 15.88 | 0.245 0.100 0.575 | -) BSC 0.625 |
| b b1 b2 b3 | 0.51 0.51 1.14 1.14 | 0.99 0.89 1.78 1.73 | 0.020 0.020 0.045 0.045 | 0.039 0.035 0.070 0.068 | | E1 e H L | 6.22 2.54 14.61 1.78 | - BSC 15.88 2.79 | 0.245 0.100 0.575 0.070 | - 0 BSC 0.625 0.110 |
| b b1 b2 b3 c | 0.51 0.51 1.14 1.14 0.38 | 0.99 0.89 1.78 1.73 0.74 | 0.020 0.020 0.045 0.045 0.015 | 0.039 0.035 0.070 0.068 0.029 | | E1 e H L L1 | 6.22 2.54 14.61 1.78 - - | - BSC 15.88 2.79 1.65 | 0.245 0.100 0.575 0.070 - - | - 0 BSC 0.625 0.110 0.066 |
| b b1 b2 b3 c c1 | 0.51 0.51 1.14 1.14 0.38 0.38 | 0.99 0.89 1.78 1.73 0.74 0.58 | 0.020 0.020 0.045 0.045 0.015 0.015 | 0.039 0.035 0.070 0.068 0.029 0.023 | | E1 e H L L1 L2 | 6.22 2.54 14.61 1.78 - - | - BSC 15.88 2.79 1.65 1.78 | 0.245 0.100 0.575 0.070 - - | - 0 BSC 0.625 0.110 0.066 0.070 |

Α

Notes

1. Dimensioning and tolerancing per ASME Y14.5M-1994.

2. Dimensions are shown in millimeters (inches).

3. Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body at datum A.

4. Thermal PAD contour optional within dimension E, L1, D1 and E1.

5. Dimension b1 and c1 apply to base metal only.

6. Datum A and B to be determined at datum plane H.

7. Outline conforms to JEDEC outline to TO-263AB.



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